

Description

The ST0521D4 is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The ST0521D4 has an ultra-low capacitance with a typical value at 0.26pF, and complies with the IEC 61000-4-2 (ESD) standard with ±15kV air and ±8kV contact discharge. It is assembled into an ultra-small 1.0x0.6x0.5mm lead-free DFN package. The small size, ultra-low capacitance and high ESD surge protection make ST0521D4 an ideal choice to protect cell phone, digital video interfaces and other high speed ports.

Mechanical Characteristics

• Package: DFN1006-2

♦ Lead Finish: NiPdAu

Case Material: "Green" Molding Compound.

♦ UL Flammability Classification Rating 94V-0

♦ Moisture Sensitivity: Level 3 per J-STD-020

Terminal Connections: See Diagram Below

♦ Marking Information: See Below

Features

- Ultra small package: 1.0x0.6x0.5mm
 Ultra low capacitance: 0.26pF typical
- Ultra low leakage: nA levelLow operating voltage: 5V
- Low clamping voltage
- 2-pin leadless package
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 Air discharge: ±20kV
 Contact discharge: ±15kV
 - IEC61000-4-4 (EFT) 40A (5/50ns)
 - IEC61000-4-5 (Lightning) 4A (8/20μs)
- RoHS Compliant

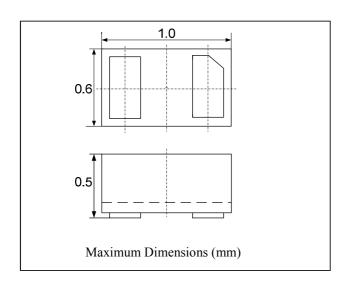
Applications

- ♦ Cellular Handsets and Accessories
- Display Ports
- MDDI Ports
- USB Ports
- Digital Video Interface (DVI)
- PCI Express and Serial SATA Ports

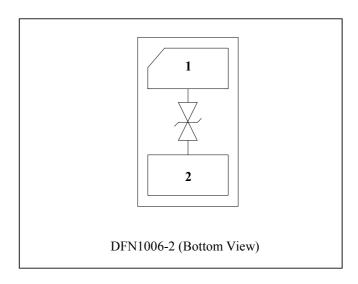
Ordering Information

Part Number	Packaging	Reel Size
ST0521D4	10000/Tape & Reel	7 inch

Dimensions



Schematic and PIN Configuration





Absolute Maximum Ratings (TA=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	100	W
Peak Pulse Current (8/20μs)	IPP	4	A
ESD per IEC 61000-4-2 (Air)	Vrap	±20	1.37
ESD per IEC 61000-4-2 (Contact)	VESD	±15	kV
Operating Temperature Range	ТЈ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

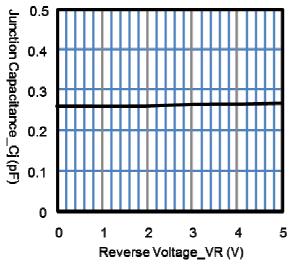
Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	
Breakdown Voltage	VBR	5.4		9	V	IT = 1 mA
Reverse Leakage Current	I_R			0.5	uA	VRWM = 5V
Clamping Voltage	Vc			12	V	IPP = $1A (8 \times 20 \mu s \text{ pulse})$
Clamping Voltage	VC			25	V	IPP = $4A (8 \times 20 \mu s \text{ pulse})$
Junction Capacitance	СЈ		0.26	0.35	pF	VR = 0V, f = 1MHz

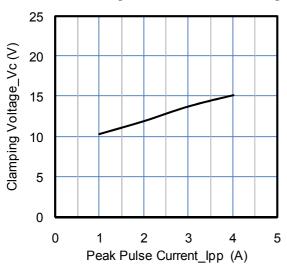
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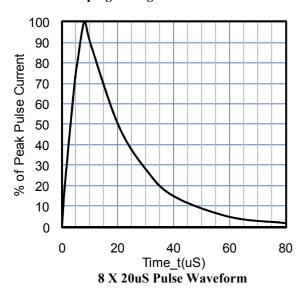
Typical Performance Characteristics (TA=25°C unless otherwise specified)

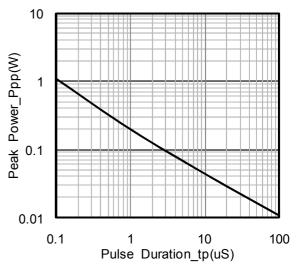


Junction Capacitance vs. Reverse Voltage

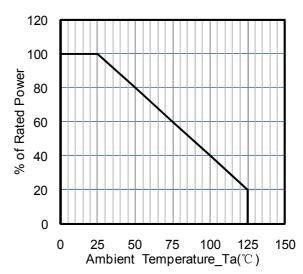


Clamping Voltage vs. Peak Pulse Current

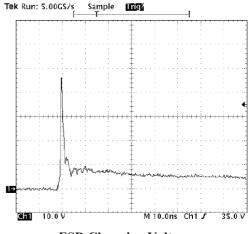




Peak Pulse Power vs. Pulse Time



Power Derating Curve



ESD Clamping Voltage

8 kV Contact per IEC61000-4-2



Applications Information

Device Connection Options

These low capacitance TVS diodes are designed to provide common mode protection for one high-speed line or differential protect tion for one line pair. The device is bidirectional and may be used on lines where the signal polarity is positive and negative.

Circuit Board Layout Recommendations for Suppression of ESD

Good circuit board layout is critical for the suppression of ESD induced transients. The following guidelines are recommended:

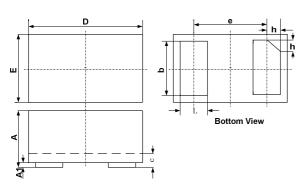
- Place the TVS near the input terminals or connectors to restrict transient coupling.
- Minimize the path length between the TVS and the protected line.
- Minimize all conductive loops including power and ground loops.
- The ESD transient return path to ground should be kept as short as possible.
- Never run critical signals near board edges.
- Use ground planes whenever possible.

Equivalent Circuit Diagram



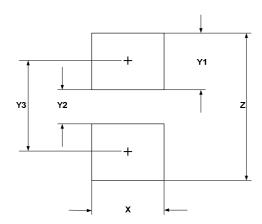


DFN1006-2 Package Outline Drawing



	DIMENSIONS					
CY ID 5	MI	LLIMETE	ERS	INCHES		
SYM	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
c	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
e	0.65 BSC			(0.026 BSC	
Е	0.55	0.60	0.65	0.022	0.024	0.026
L	0.20	0.25	0.30	0.008	0.010	0.012
h	0.07	0.12	0.17	0.003	0.005	0.007

Suggested Land Pattern



GVD 5	DIMENSIONS			
SYM	MILLIMETERS	INCHES		
X	0.60	0.024		
Y1	0.50	0.020		
Y2	0.30	0.012		
Y3	0.80	0.032		
Z	1.30	0.052		

Contact Information

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